



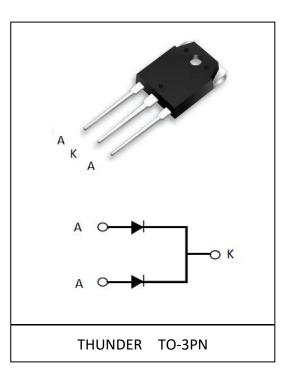
Thunder High Power Products

FRED Ultrafast Soft Recovery Diode, 100A

Features:

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I_R value
- High surge capacity
- Epitaxial chip construction

Product Summary		
VR	600 V	
IF(AV)	2*50A	
trr	32ns	



Description/Applications

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

Absolute Maximum Ratings

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	Vrrm		600	V
Continuous forward current	lf(AV)	Tc =110°C	100	
Single pulse forward current	Ifsm	Tc =25°C	600	A
Maximum repetitive forward current	IFRM	Square wave, 20kHZ	150	
Operating junction	Тј		175	°C
Storage temperatures	Tstg		-55 to +175	°C





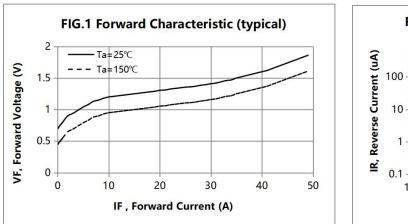
Electrical characteristics (Ta=25°C unless otherwise specified)

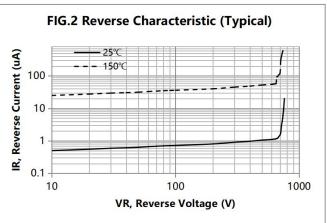
Parameter	Symbol	Test Conditions	Min	Тур.	Max.	Units	
Breakdown voltage	Vbr,	Ir=100µA	600				
Blocking voltage	V _R		000				
Forward voltage (Per Diode)	VF	IF=50A		1.55	1.80	V	
		IF=50A, Tj =125°C		1.3	1.70		
Reverse leakage current(Per Diode)		Vr= Vrrm			30		
	IR	Tj=150°C, Vr=600V			300	μA	
Reverse recovery time(Per Diode)	trr	I _F =0.5A, I _R =1A, I _{RR} =0.25A		45	65		
		I _F =1A,V _R =30V, di/ <i>dt</i> =200A/us		32	45	ns	

Thermal characteristics

Paramter	Symbol	Тур	Units
Junction-to-Case	R _{θJC}	0.7	°C/W

Electrical performance (typical)

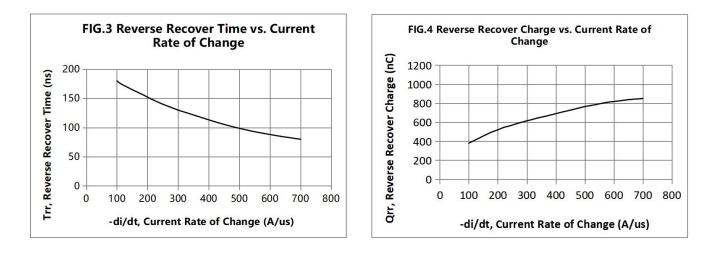


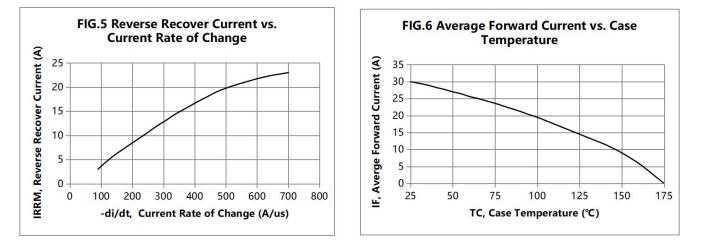


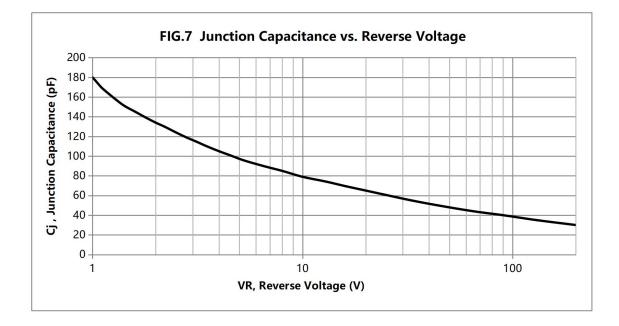


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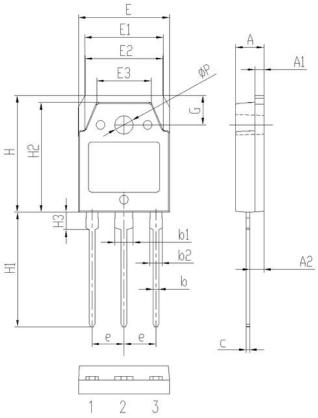








Package Information



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Symbol	Dimensions(millimeters)		
Cymbol	Min.	Max.	
А	4.60	5.00	
A1	1.30	1.70	
A2	2.20	2.60	
b	0.80	1.20	
b1	2.90	3.30	
b2	1.90	2.30	
С	0.40	0.80	
е	5.25	5.65	
E	15.3	15.7	
E1	13.2	13.6	
E2	13.1	13.5	
E3	9.10	9.50	
Н	19.7	20.1	
H1	19.1	20.1	
H2	18.3	18.7	
H3	2.80	3.20	
G	4.80	5.20	
ΦР	3.00	3.40	

Notice

Thunder Microelectronics Incorporated Limited reserves the right to make changes without further notice to any products or specifications herein. When use the product, be sure to obtain the latest specification.

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